

*East Search
for paper no. 10*

L Number	Hits	Search Text	DB	Time stamp
1	0	("49396905646516").pn. and jp-2000068487-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/04 11:42
2	7	("4939690" "5646516").pn. jp-2000068487-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/04 11:49
-	6	"6268629"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 10:23
-	241	select\$3 adj transistor and (distribution doping impurity) near2 (profile distribution)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 15:28
-	194	(select\$3 adj transistor and (distribution doping impurity) near2 (profile distribution)) and memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 16:29
-	578	(438/258).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 16:30
-	320	(438/266).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 16:30
-	179	(257/326).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 17:46
-	5	("3893152" "4622570" "4959812" "5150179" "5280446").PN.	USPAT	2003/09/02 17:00
-	16	5677556.URPN.	USPAT	2003/09/02 17:00
-	13	("4939690" "4959812" "5253206" "5321699" "5323039" "5355330" "5357462" "5365098" "5477068" "5508957" "5592001" "5677556" "5698879").PN.	USPAT	2003/09/02 17:17
-	6	5949101.URPN.	USPAT	2003/09/02 17:17
-	6	("4203158" "4233526" "4467453" "4500975" "4580247" "4648074").PN.	USPAT	2003/09/02 17:30
-	61	4939690.URPN.	USPAT	2003/09/02 17:30
-	269	channel with impurity adj profile	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 17:47
-	39	(channel with impurity adj profile) and selection	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/02 17:47

-	29	channel nearl impurity adj profile	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 17:47
-	12	("5293337" "5493139" "5677556" "5949101" "5822243" "4939690").pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 10:29
-	1	(impurity doping) with (concentration profile distribution) with relative with (selection access) with (memory cell)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 10:33
-	60	(impurity doping) with (concentration profile distribution) with (higher lower) with (selection access) with (memory cell)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 10:33
-	25	(impurity doping) with (concentration profile distribution) with (higher lower) with (selection access) with (memory cell) with channel	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 10:44
-	97	(impurity doping) with (concentration profile distribution) same (higher lower) same (selection access) same (memory cell) same channel	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 10:45
-	72	((impurity doping) with (concentration profile distribution) same (higher lower) same (selection access) same (memory cell) same channel) not ((impurity doping) with (concentration profile distribution) with (higher lower) with (selection access) with (memory cell) with channel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 11:31
-	5	selection adj transistor same memory same channel with (doping impurity) with (profile distribution concentration) with (lower higher)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 11:38
-	4	(selection adj transistor with channel same memory with channel same (doping impurity) with (profile distribution concentration) with (lower higher)) and (selection adj transistor with channel same memory with channel and channel with (doping impurity) with (profile distribution concentration) with (lower higher))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 11:42
-	14	(selection adj transistor with channel same memory with channel same (doping impurity) with (profile distribution concentration) with (lower higher)) (selection adj transistor with channel same memory with channel and channel with (doping impurity) with (profile distribution concentration) with (lower higher))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 11:42
-	4	selection adj transistor with channel same memory with channel same (doping impurity) with (profile distribution concentration) with (lower higher)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 11:45
-	14	selection adj transistor with channel same memory with channel and channel with (doping impurity) with (profile distribution concentration) with (lower higher)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 11:50

-	19	selection adj transistor with channel and memory with channel and channel with (doping impurity) with (profile distribution concentration) with (lower higher)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 16:04
-	2	jp-2000068487-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 16:06
-	1	2000-263183.NRAN.	DERWENT; IBM TDB	2003/09/03 16:06
-	0	1998jp-230334.ap,prai.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 16:06
-	1	1998jp-0230334.ap,prai.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 16:09
-	1	1998jp-0240334.ap,prai.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 16:39
-	21	selection adj transistor with memory with distance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 16:45
-	36	selection adj transistor with memory with space	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 16:57
-	26	selection with transistor with memory with distance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 16:59
-	5	(selection with transistor with memory with distance) not (selection adj transistor with memory with distance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 16:58
-	12	access adj transistor with memory with distance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 17:08
-	24	selection near2 transistor with memory with distance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 17:10
-	16	selection near2 transistor with memory with spaced	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 17:10